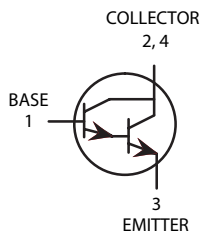
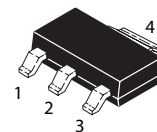


Darlington NPN Silicon Planar Epitaxial Transistor

(Pb) Lead(Pb)-Free



1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR



SOT-223

ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	30	V
Collector-Base Voltage	V _{CBO}	30	V
Emitter-Base Voltage	V _{EBO}	10	V
Collector Current (DC)	I _{C(DC)}	300	mA
Total Device Dissipation T _A =25°C	P _D	2	W
Junction Temperature	T _j	150	°C
Storage, Temperature	T _{stg}	-55 to +150	°C

Device Marking

PZTA14=A14

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I _C = 1mA , I _B =0)	V _{(BR)CEO}	30	-	V
Collector-Base Breakdown Voltage (I _C =100μA , I _E =0)	V _{(BR)CBO}	30	-	V
Emitter-Base Breakdown Voltage (I _E = 10 μA , I _C =0)	V _{(BR)EBO}	10	-	V
Collector-Base Cutoff Current (V _{CB} = 30V)	I _{CBO}	-	100	nA
Emitter-Base Cutoff Current (V _{EB} = 10Vdc , I _C =0)	I _{EBO}	-	100	nA

NOTE: 1.Device mounted on an epoxy printed circuit board 1.575 inches×1.575 inches×0.059 inches; mounting pad for the collector lead min. 0.93 inches²

ELECTRICAL CHARACTERISTICS— Continued ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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DC CHARACTERISTICS

DC Current Gain ($I_C = 10\text{ mA}, V_{CE} = 5\text{ V}$) ($I_C = 100\text{ mA}, V_{CE} = 5\text{ V}$)	h_{FE1} h_{FE2}	10K 20K	- -	- -	-
Collector-Emitter Saturation Voltage ($I_C = 100\text{ mA}, I_B = 0.1\text{ mA}$)	$V_{CE(sat)}$	-	-	1.5	V
Base-Emitter Saturation Voltage ($I_C = 100\text{ mA}, V_{CE} = 5\text{ V}$)	$V_{BE(on)}$	-	-	2	V

DYNAMIC CHARACTERISTICS

Current-Gain-Bandwidth Product ($I_C = 10\text{ mA}, V_{CE} = 5\text{ V}, f = 100\text{ MHz}$)	f_T	125	-	-	MHz
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Characieristics Curve

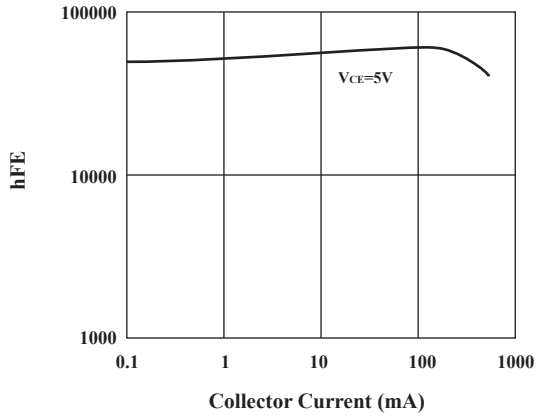


Fig.1 Current Gain & Collector Current

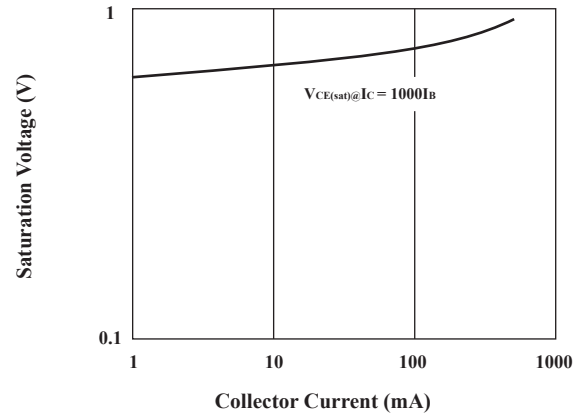


Fig.2 Saturation Voltage & Collector Current

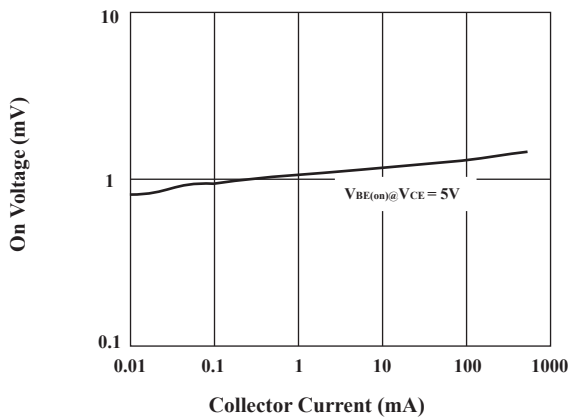


Fig.3 On Voltage & Collector Current

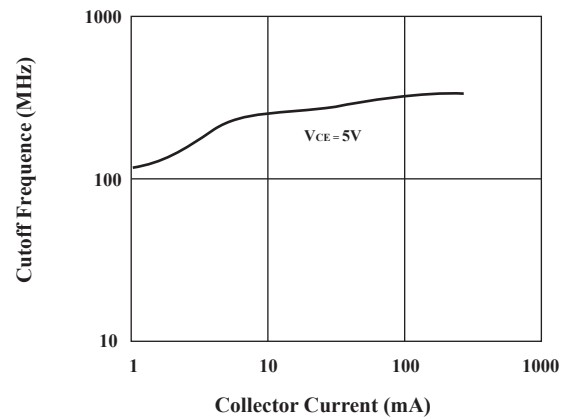


Fig.4 Cutoff Frequency & Collector Current

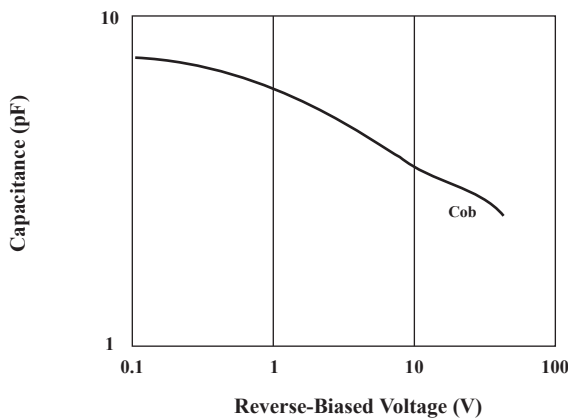


Fig.5 Capacitance & Reverse-Biased Voltage

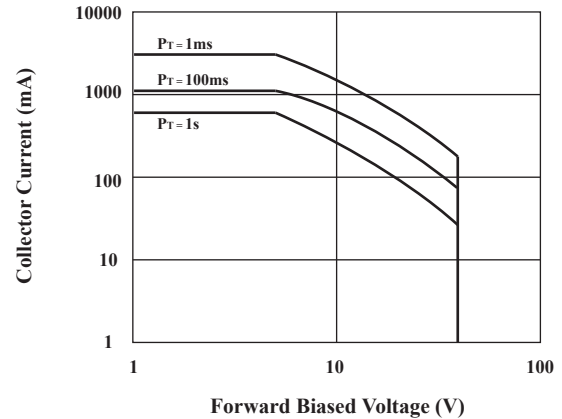
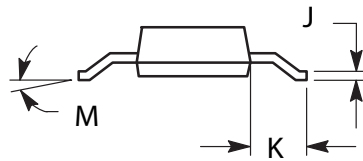
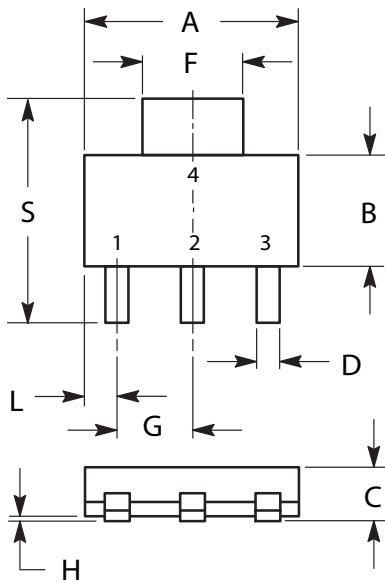


Fig.6 Safe Operating Area

SOT-223 Outline Dimensions

unit:mm



DIM	MILLIMETERS	
	MIN	MAX
A	6.30	6.70
B	3.30	3.70
C	1.50	1.75
D	0.60	0.89
F	2.90	3.20
G	2.20	2.40
H	0.020	0.100
J	0.24	0.35
K	1.50	2.00
L	0.85	1.05
M	0°	10°
S	6.70	7.30